NSN 5962-01-226-6879

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-226-6879 **Body Length:** 0.960 inches **Body Width:** 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 794.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Bipolar and programmable and schottky **Inclosure Material:** Plastic or ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** D-6 mil-m-38510 **Terminal Surface Treatment:** Gold Voltage Rating And Type Per Characteristic: 7.0 volts power source **Memory Device Type:** Rom **Precious Material And Location:** Terminal surface option gold **Precious Material:** Gold **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 18 printed circuit Shelf Life: N/a

Unit Of Measure:

NSN 5962-01-226-6879

Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

A458a0